GB2X50MPS17-227
1700V 100A SiC Schottky MPS™ Diode

GeneSiC SEMICONDUCTOR

Silicon Carbide Schottky Diode

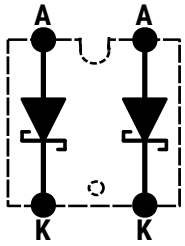
V_{RRM}	=	1700 V
$I_{F(T_C = 134°C)}$	=	100 A *
Q_C	=	1076 nC *

Features

- Low V_F for High Temperature Operation
- Enhanced Surge and Avalanche Robustness
- Superior Figure of Merit Q_C/I_F
- Low Thermal Resistance
- Low Reverse Leakage Current
- Temperature Independent Fast Switching
- Positive Temperature Coefficient of V_F
- Low V_F for High Temperature Operation

Package

SOT-227



RoHS

REACH

Advantages

- Improved System Efficiency
- High System Reliability
- Optimal Price Performance
- Reduced Cooling Requirements
- Increased System Power Density
- Zero Reverse Recovery Current
- Easy to Parallel without Thermal Runaway
- Improved System Efficiency

Applications

- EV Fast Chargers
- Solar Inverters
- Wind Energy Converters
- Train Auxiliary Power Supplies
- High Frequency Rectifiers
- Switched Mode Power Supplies
- Motor Drives
- Pulsed Power

Absolute Maximum Ratings (At T_C = 25°C Unless Otherwise Stated)

Parameter	Symbol	Conditions	Values	Unit	Note
Repetitive Peak Reverse Voltage (Per Leg)	V_{RRM}		1700	V	
Continuous Forward Current (Per Leg / Per Device)	I_F	T_C = 75°C, D = 1 T_C = 100°C, D = 1 T_C = 134°C, D = 1	84 / 168 71 / 142 50 / 100	A	Fig. 4
Non-Repetitive Peak Forward Surge Current, Half Sine Wave (Per Leg)	$I_{F,SM}$	T_C = 25°C, t_P = 10 ms T_C = 150°C, t_P = 10 ms	500 400	A	
Repetitive Peak Forward Surge Current, Half Sine Wave (Per Leg)	$I_{F,RM}$	T_C = 25°C, t_P = 10 ms T_C = 150°C, t_P = 10 ms	300 210	A	
Non-Repetitive Peak Forward Surge Current (Per Leg)	$I_{F,MAX}$	T_C = 25°C, t_P = 10 µs	2500	A	
i^2t Value (Per Leg)	$\int i^2dt$	T_C = 25°C, t_P = 10 ms	1250	A^2s	
Non-Repetitive Avalanche Energy (Per Leg)	E_{AS}	L = 1.0 mH, I_{AS} = 50 A	1301	mJ	
Diode Ruggedness (Per Leg)	dV/dt	V_R = 0 ~ 1360 V	200	V/ns	
Power Dissipation (Per Leg / Per Device)	P_{TOT}	T_C = 25°C	387 / 774	W	Fig. 3
Operating and Storage Temperature	T_j , T_{stg}		-55 to 175	°C	

** Per Device*

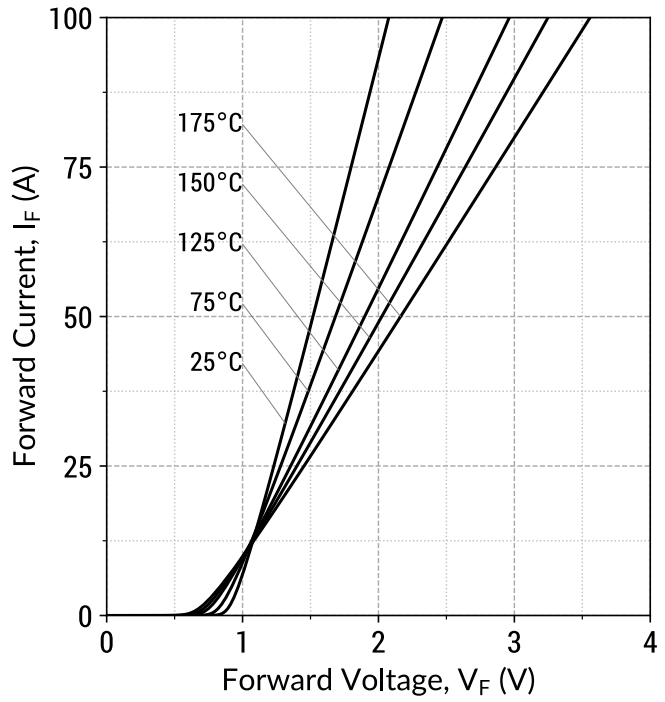
Electrical Characteristics (Per Leg)

Parameter	Symbol	Conditions		Values			Unit	Note
				Min.	Typ.	Max.		
Diode Forward Voltage	V_F	I_F = 50 A, T_j = 25°C			1.5	1.8	V	Fig. 1
		I_F = 50 A, T_j = 175°C			2.1			
Reverse Current	I_R	V_R = 1700 V, T_j = 25°C			2	10	µA	Fig. 2
		V_R = 1700 V, T_j = 175°C			42			
Total Capacitive Charge	Q_C	$I_F \le I_{F,MAX}$ dI_F/dt = 200 A/µs	V_R = 600 V		368		nC	Fig. 7
			V_R = 1200 V		538			
Switching Time	t_S		V_R = 600 V		< 10		ns	
			V_R = 1200 V					
Total Capacitance	C	V_R = 1 V, f = 1MHz			4701		pF	Fig. 6
		V_R = 1200 V, f = 1MHz			259			

Thermal/Package Characteristics

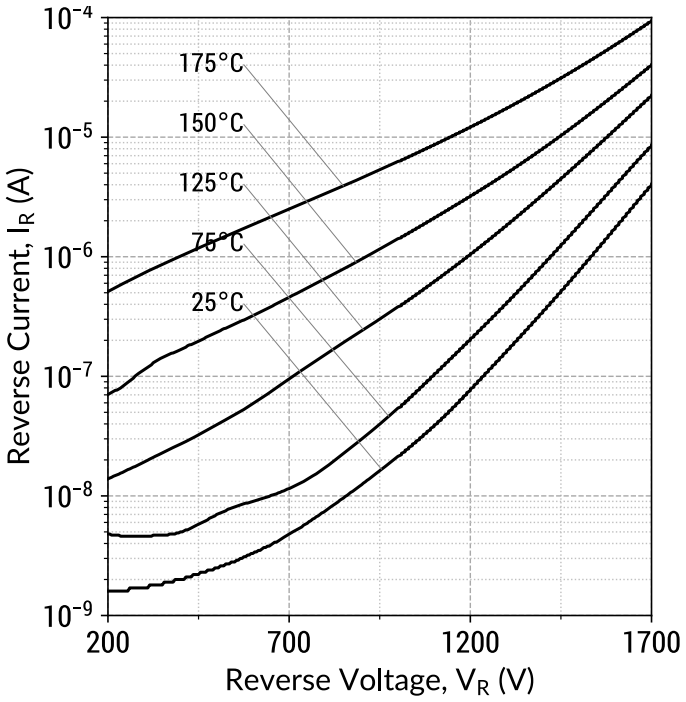
Parameter	Symbol	Conditions	Values			Unit	Note
			Min.	Typ.	Max.		
Thermal Resistance, Junction - Case (Per Leg)	R_{thJC}			0.39		°C/W	Fig. 9
Weight	W_T			28.0		g	
Mounting Torque	T_M	Screws to Heatsink			1.5	Nm	
Terminal Connection Torque	T_C	M4 Screws			1.3	Nm	
Isolation Voltage(RMS)	V_{ISO}	t = 1s (50/60 Hz)		3000		V	
		t = 60s (50/60 Hz)		2500			
Creepage Distance on Surface	d_{Ctt}	Terminal to Terminal		10.5		mm	
	d_{Ctb}	Terminal to Backside		8.5			
Striking Distance Through Air	d_{Stt}	Terminal to Terminal		3.2		mm	
	d_{Stb}	Terminal to Backside		6.8			

Figure 1: Typical Forward Characteristics (Per Leg)



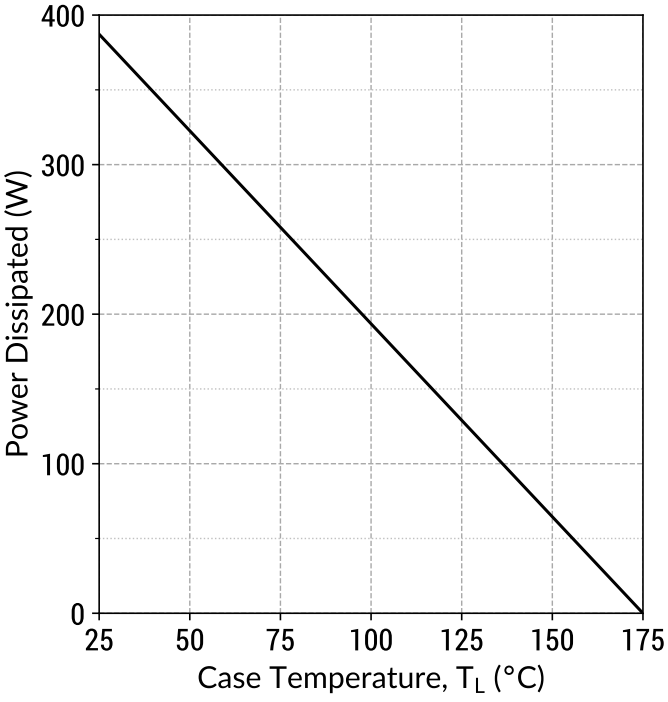
$I_F = f(V_F, T_j)$; $t_P = 250\ \mu s$

Figure 2: Typical Reverse Characteristics (Per Leg)



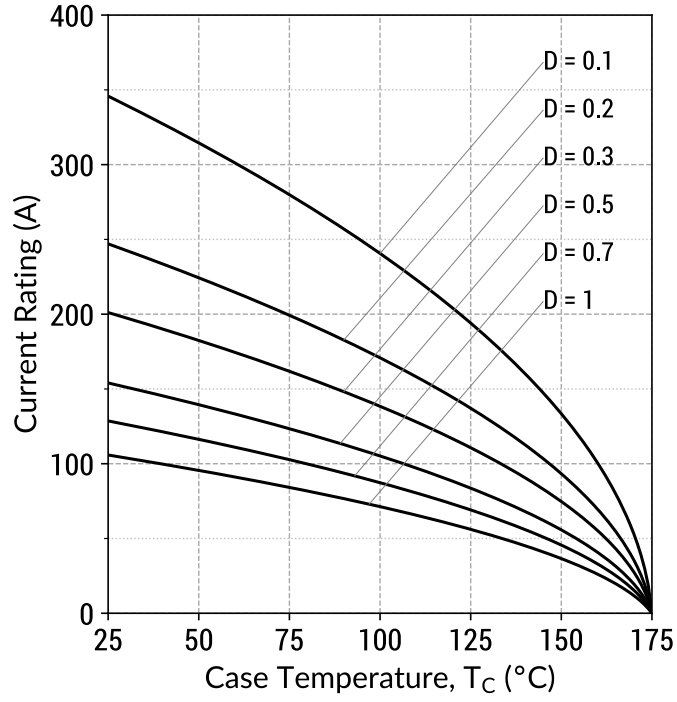
$I_R = f(V_R, T_j)$

Figure 3: Power Derating Curves (Per Leg)



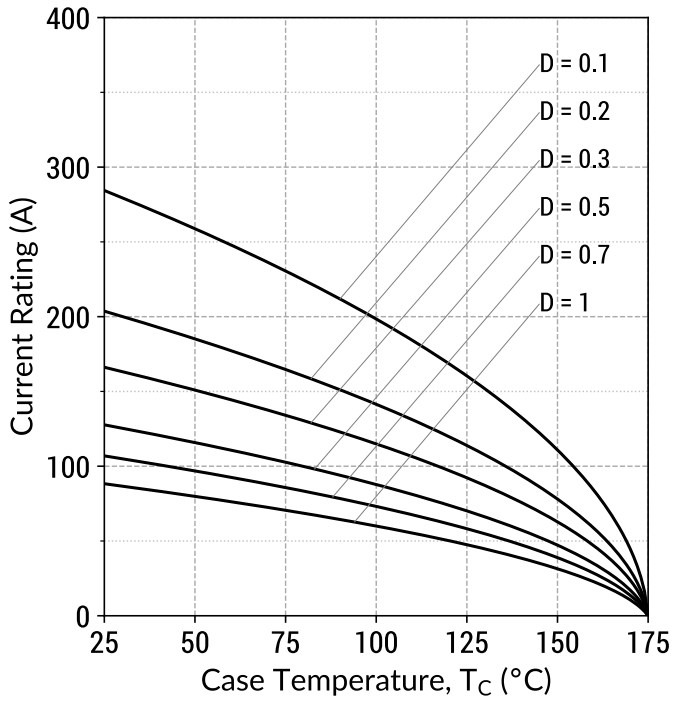
$P_{TOT} = f(T_C)$; $T_j = 175°C$

Figure 4: Current Derating Curves (Typical V_F) (Per Leg)



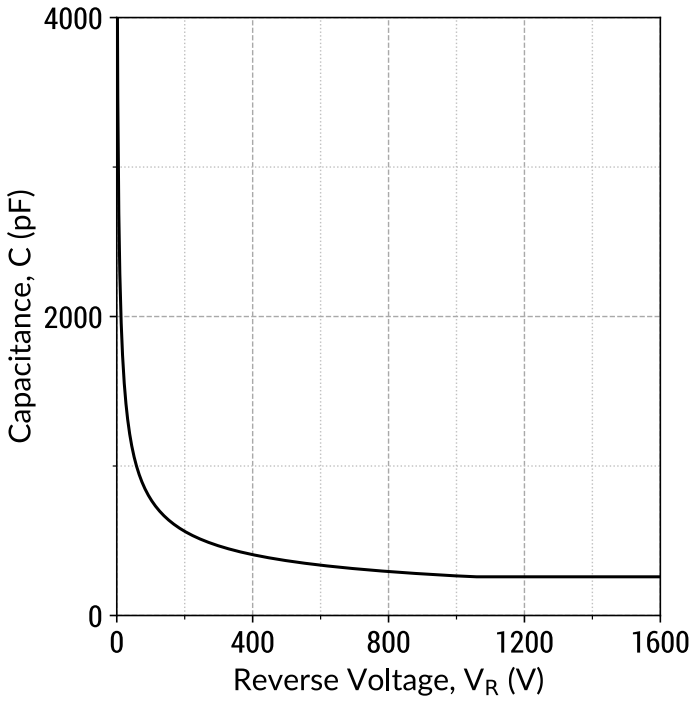
$I_F = f(T_C)$; $D = t_P/T$; $T_j \leq 175°C$; $f_{SW} > 10kHz$

Figure 5: Current Derating Curves (Maximum V_F) (Per Leg)



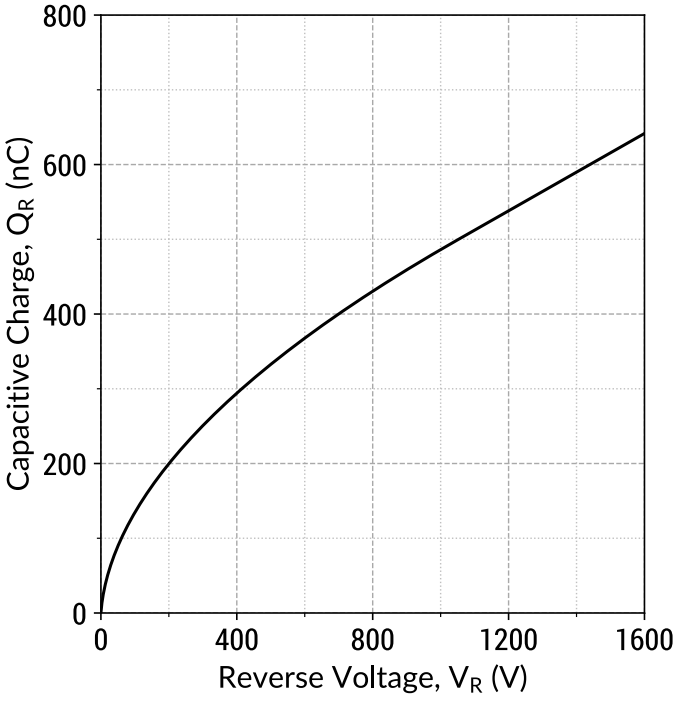
$I_F = f(T_C)$; $D = t_P/T$; $T_j \leq 175°C$; $f_{SW} > 10kHz$

Figure 6: Typical Junction Capacitance vs Reverse Voltage Characteristics (Per Leg)



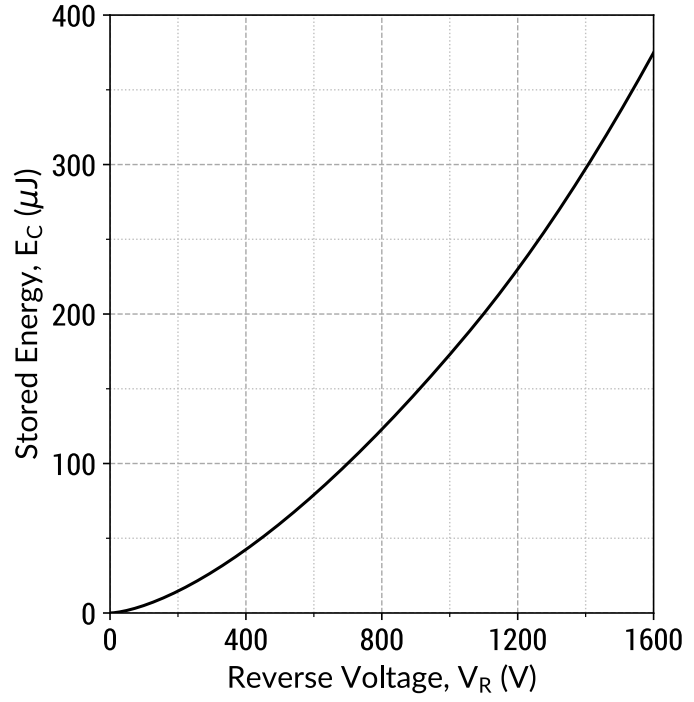
$C = f(V_R)$; $f = 1MHz$

Figure 7: Typical Capacitive Charge vs Reverse Voltage Characteristics (Per Leg)



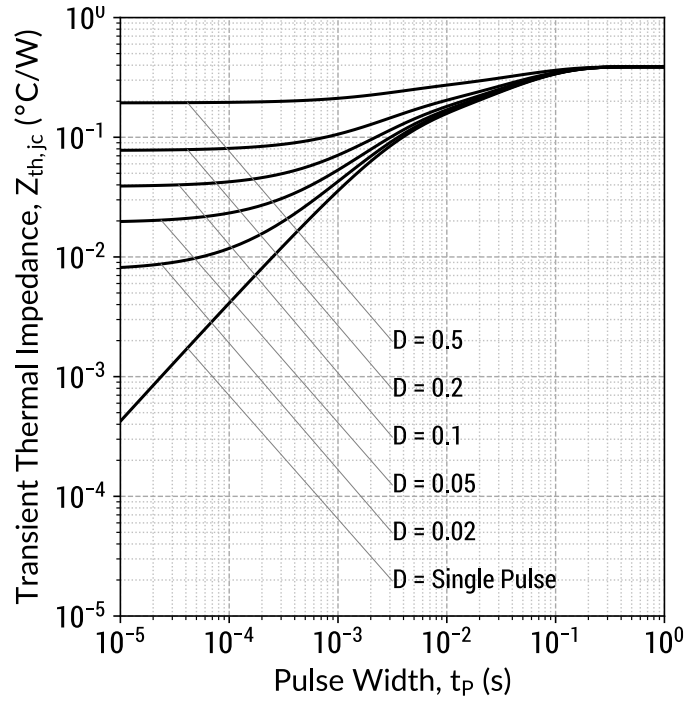
$Q_C = f(V_R)$; $f = 1MHz$

Figure 8: Typical Capacitive Energy vs Reverse Voltage Characteristics (Per Leg)



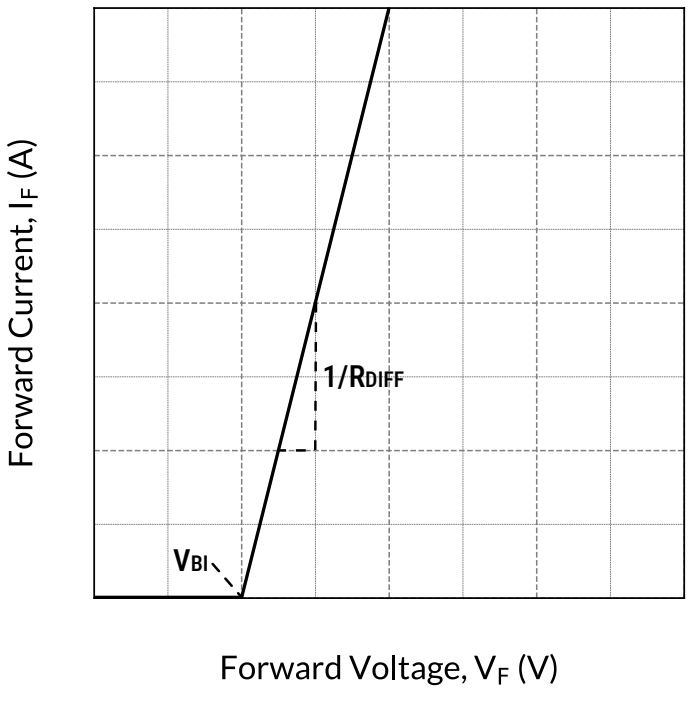
$E_C = f(V_R)$; $f = 1MHz$

Figure 9: Transient Thermal Impedance (Per Leg)



$Z_{th,jc} = f(t_P,D)$; $D = t_P/T$

Figure 10: Forward Curve Model (Per Leg)



$I_F = f(V_F,T_j)$

Forward Curve Model Equation:

$I_F = (V_F - V_{BI})/R_{DIFF}$ (A)

Built-In Voltage (V_{BI}):

$V_{BI}(T_j) = m \times T_j + n$ (V)

m = -0.00128 (V/°C)

n = 0.99 (V)

Differential Resistance (R_{DIFF}):

$R_{DIFF}(T_j) = a \times T_j^2 + b \times T_j + c$ (Ω)

a = 2.03e-07 (Ω/°C^2)

b = 7.11e-05 (Ω/°C)

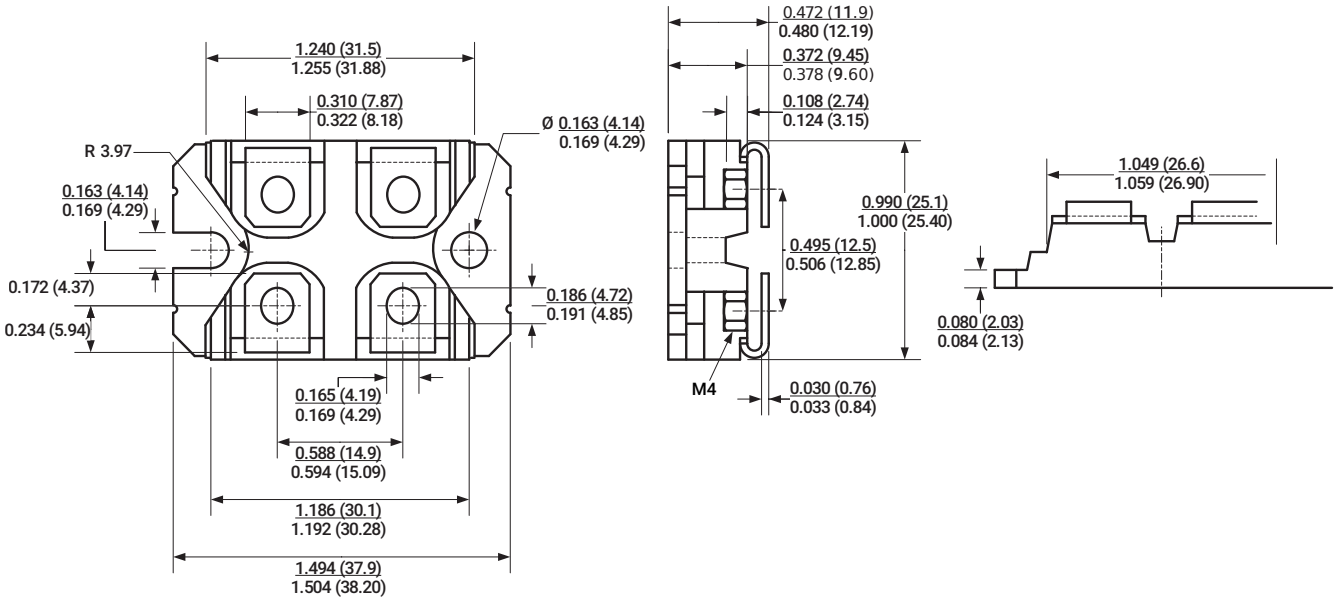
c = 0.0093 (Ω)

Forward Power Loss Equation:

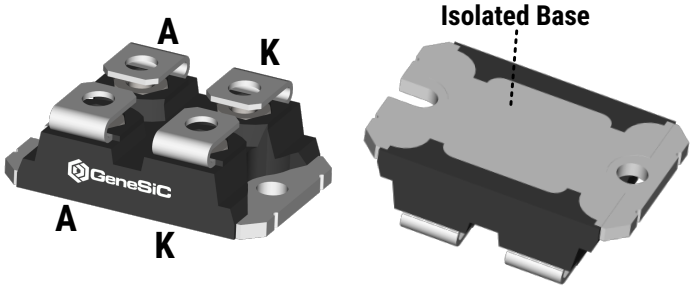
$P_{LOSS} = V_{BI}(T_j) \times I_{AVG} + R_{DIFF}(T_j) \times I_{RMS}^2$

Package Dimensions

SOT-227 Package Outline



Package View



NOTE

1. CONTROLLED DIMENSION IS INCH. DIMENSION IN BRACKET IS MILLIMETER.
2. DIMENSIONS DO NOT INCLUDE END FLASH, MOLD FLASH, MATERIAL PROTRUSIONS.

Compliance

RoHS Compliance

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS 2), as adopted by EU member states on January 2, 2013 and amended on March 31, 2015 by EU Directive 2015/863. RoHS Declarations for this product can be obtained from your GeneSiC representative.

REACH Compliance

REACH substances of high concern (SVHCs) information is available for this product. Since the European Chemical Agency (ECHA) has published notice of their intent to frequently revise the SVHC listing for the foreseeable future, please contact a GeneSiC representative to insure you get the most up-to-date REACH SVHC Declaration. REACH banned substance information (REACH Article 67) is also available upon request.

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Revision History

- Rev 21/Mar: Updated with most recent data
- Supersedes: Rev 20/Apr, Rev 20/Aug

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